

## IN THE SPECIFICATION

Please amend the paragraph beginning at page 2, line 7, and ending at page 2, line 23, as follows:

--For example, as reported in ~~Optical confinement effect in a-SiGe Solar Cell on 29p-MF-22 Stainless Steel~~, Inoue et al., "Optical confinement in a-SiGe solar cells on stainless steel substrates", 29p-MF-2, Autumn in 1990, 51st Applied Physics Society Scientific Lectures, Lecture Collections, p.747 (hereinafter Non-patent Literature 1), and ~~P-IA-15 a-SiC/a-Si/a-SiGe Multi-bandgap Stacked Solar Cells with Bandgap Profiling~~, in Sannomiya et al., P-IA-15, "a-SiC/a-Si/a-SiGe Multi-Bandgap Stacked Solar Cells with Bandgap Profiling", Technical Digest of The International PVSEC-5, ~~kyoto, Japan, p.381, 1990 Kyoto, Japan, 1990, pp. 387-390~~ (hereinafter Non-patent Literature 2), studies are made on reflectance and textured structure in respect of reflection layers constituted of silver atoms. In these examples, the reflection layer is formed by double-layer deposition of silver at substrate temperature changed for each layer, to form effective unevenness, and this has achieved enhancement of short-circuit current in virtue of the optical confinement effect, in combination with a zinc oxide film, as so reported.--